

**FACSIMILE TRANSMISSION**

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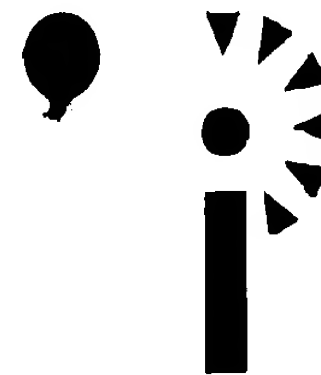
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**Application of**

Applicants : Chandra V. Mouli and Ceredig Roberts

Serial No. : 09/648,044

Filed : August 25, 2000

Confirm No. : 6800

Title : **METHOD AND DEVICE TO REDUCE GATE-INDUCED DRAIN  
LEAKAGE (GIDL) CURRENT IN THIN GATE OXIDE MOSFETs**

Docket No. : MIO 0054 PA

Examiner : O. Nadav

Art Unit : 2811

**CONFIDENTIAL ATTORNEY CLIENT PRIVILEGED FACSIMILE COMMUNICATIONS**

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## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

## Application of

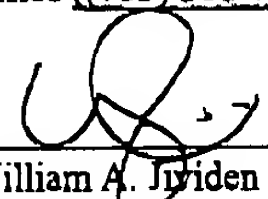
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Assistant Commissioner for Patents  
Washington, D.C. 20231

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William A. Jividen 42,695  
Reg. No.

Sir:

AMENDMENT

This paper is being filed in response to the Office Action mailed December 5, 2001, thereby having a non-fee response date of no later than March 5, 2002. Additionally, this paper is being filed in response to the Office communication mailed February 13, 2002 regarding payment of fee. Reconsideration and reexamination are respectfully requested in light of the amendments and remarks below.

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In the Drawing

FEB 22 2002

The Applicant encloses herewith new FIG. 3E illustrating the subject matter described in the specification and claims of the present application for approval by the examiner. It is respectfully submitted that the presently proposed figure drawing more accurately illustrate the recited subject matter of the present invention. No new matter has been entered.

In the Specification

Attached hereto as Appendix A is a marked up reproduction of the changes made to the specification and claims by the current amendments. Additions have been underscored and deletions have been stricken.